# LM5642 Evaluation Board

National Semiconductor Application Note 1292 Chris Richardson September 2003



#### Introduction

The LM5642 IC is a dual channel, current-mode, synchronous buck converter controller. It can handle input voltages of up to 36V and delivers two independent output voltages from 1.23V up to 90% of the input voltage. Current sensing can be done using a dedicated resistor or using the R<sub>DS(ON)</sub> of the high-side FET. This application note describes the dedicated evaluation PCBs that are available for both meth-

#### Resistor Sense PCB

The first, more common method of sensing current in current-mode controllers is with an external sense resistor, placed in series with the high-side FET of each channel. Sense resistors provide an accurate voltage as the load current passes through them, and have stable, linear resistance change with temperature. As shipped the Resistor Sense PCB is designed to deliver 1.8V on Channel 1 at a maximum current of 7A, and 3.3V on Channel 2 at a maximum current of 4A. The input voltage can vary anywhere from 5.5 to 36V. The board has been designed to be flexible and allow many other circuit configurations by replacing the original components with user selected ones. Figure 1 shows the circuit diagram representing the standard BOM that comes with the PCB. Table 1 lists all the components that are used for this standard configuration BOM. Figure 2 shows the complete circuit diagram with all extra footprints. Two SPST switches **S1** and **S2** are provided to turn the two channels of the converter on and off. The standard BOM that comes with the LM5642 Resistor Sense evaluation board uses  $10m\Omega$  current sense resistors (R7 for Channel 1, R15 for Channel 2) to provide independent feedback signals to the IC. The board provides additional resistor and capacitor footprints for noise filtering, ringing control, and to enable operation at low input voltages.

#### Current Sense Filters

R-C filters have been added to the current sense amplifier inputs of the Resistor Sense evaluation board, comprised of components C3, C4, C14, C15, R2, R6, and R16. These resistors and capacitors reduce the sensitivity to switching noise, especially during high currents, load-transients, and circuits with short on-times.

# **Parallel Operation**

The two channels of the LM5642 Resistor Sense evaluation board can be paralleled to provide one high current rail. At the nominal switching frequency of 200kHz the converter will run 180° out-of-phase. Care must be taken when using this feature combined with the frequency synchronization, as the two channels of the converter are no longer 180° out-ofphase when the frequency is above or below 200kHz. The two feedback inputs FB1 and FB2 should be tied together by soldering a  $0\Omega$  resistor in the position marked  ${\bf J1}$  on the bottom side of the PCB. The two COMP pins should be tied together by soldering a  $0\Omega$  resistor in the position **J3**. The

ON/SS1 and ON/SS2 pins must also be connected using a  $0\Omega$  resistor in the position **J2**. One of the two SPDT switches S1 and S2 should be left 'ON' and the other used to turn the converter off and on. Finally, the two outputs VO1 and VO2 must be tied together by the user, external to the PCB. Only one of the two resistor divider networks (R10/R11 or R19/ R20) and only one of the compensation networks should be used. (C18/C19/R22/R23) or C20/C21R24/R25.

# V<sub>DS</sub> Sense PCB

The LM5642 IC offers a second current sensing mechanism that uses the R<sub>DS(ON)</sub> of the high-side FET to sense the load current. This method reduces the parts count on the BOM, however the R<sub>DS(ON)</sub> of a FET is not as tightly controlled as a sense resistor, and suffers from non-linear changes in resistance with temperature. As a result, the IC is more sensitive to noise in this mode, especially at input voltages above 30V. The maximum recommended current using VDS sensing is 5A per channel. The VDS Sense board has been designed to deliver 1.8V on Channel 1 with a maximum current of 5A, and 3.3V on Channel 2 with a maximum current of 4A. Figure 3 shows the circuit diagram representing the standard BOM that comes with the PCB. Table 2 lists all the components that are used for this standard configuration BOM. Figure 4 shows the complete circuit diagram with all extra footprints.

# Frequency Synchronization

A connection point labeled 'SYNC' is available on both versions of the LM5642 evaluation boards in order to adjust the switching frequency of the IC between 150 and 250kHz. Both CMOS and TTL level square wave signals can be used. The SYNC input has a minimum low-to-high transition threshold of 2.0V and a maximum high-to-low threshold of 0.8V. The SYNC pin is grounded by a  $220k\Omega$  pull-down resistor.

# Low Input Voltage Operation

When the input voltage is between 4.5V and 5.5 on either evaluation board, a  $4.7\Omega$  resistor should be installed in position R26. This will ensure than VLIN5 does not fall below the UVLO threshold of the IC. When R26 is in place the input voltage must not exceed 5.5V.

# Gate Drive Current Limiting

The LM25642 IC includes powerful gate drivers which can drive small FETs at high speed, often inducing noise or ringing into the board. Slowing the gate drivers can help reduce this noise by increasing the drain current transition time. While slowing the gate drives can help suppress noise, it also increases switching losses and gate-charge losses in the top FET. Slowing of the gate drives can be accomplished with resistors in series with the CBOOT1 and CBOOT2 pins. (R9,R18) Placing resistors in series with the CBOOT pins will

# **Gate Drive Current Limiting**

(Continued)

slow the top FET rise time only. Generally the values for gate drive limiting resistors are between 1 and  $5\Omega$ . **R9** and **R18** are  $0\Omega$  by default.

## Parallel Low-Side Schottky Diode

The LM5642 evaluation boards include footprints for Schottky diodes **D4** and **D5** (SMB footprint or smaller) in parallel to the low side FETs. Placing these diodes on the PCB can improve efficiency because Schottky diodes have a lower forward voltage drop and lower reverse recovery charge than the parasitic diode of the bottom FET.

#### Parallel Low-Side FET

Footprints Q3 and Q6 have been placed on both boards so that two SO-8 N-FETs can be placed in parallel for the low-side of each channel. Paralleling FETs reduces the

 $\rm R_{DS(ON)}$  of the system and spreads the heat dissipated by the load current over two packages. This is especially important for converters with high input voltage and low output voltage, where the low duty cycle forces the low side FET or FETs to carry the load current for a much greater percentage than the high-side FET.

## **Additional Footprints**

Additional footprints are provided to add more surface mount or through-hole capacitors (with 3.5 or 5mm lead spacing) in parallel to the input and output capacitors.

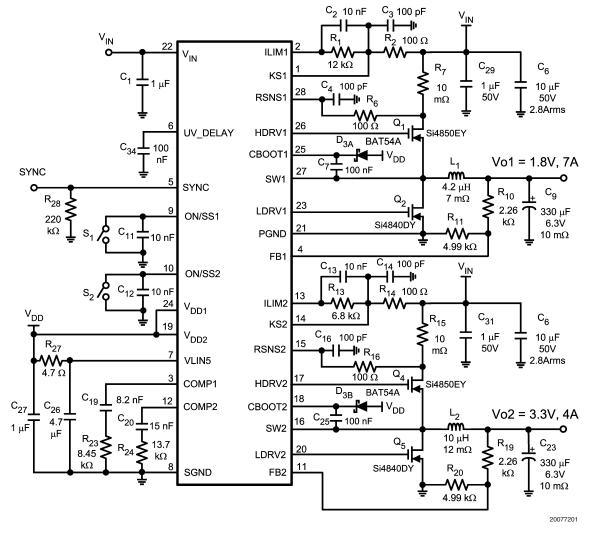


FIGURE 1. Standard Resistor Sense Circuit

# Additional Footprints (Continued)

# **TABLE 1. Standard Resistor Sense Bill Of Materials**

| ID                | Part Number       | Туре                        | Size             | Parameters  | Qty | Vendor |
|-------------------|-------------------|-----------------------------|------------------|---|-----|--------|
| U1                | LM5642            | Dual Synchronous Controller | TSSOP-28         |   | 1   | NSC    |
| Q1, Q4            | Si4850EY          | N-MOSFET                    | SO-8             | 60V   | 2   | Vishay |
| Q2, Q5            | Si4840DY          | N-MOSFET                    | SO-8             | 40V   | 2   | Vishay |
| D3                | BAT54A            | Schottky Diode              | SOT-23           | 30V   | 1   | ON     |
| L1                | RLF12560T-4R2N100 | Inductor                    | 12.5x12.5x 6mm   | 4.2μH, 7mΩ, 10A                                       | 1   | TDK    |
| L2                | RLF12545T-100M5R1 | Inductor                    | 12.5x12.5x 4.5mm | 10μH, 12mΩ, 5.1A                                      | 1   | TDK    |
| C1, C29, C31      | C3216X7R1H105K    | Capacitor                   | 1206             | 1μF, 50V  | 3   | TDK    |
| C3, C4, C14, C15  | VJ1206Y101KXXAT   | Capacitor                   | 1206             | 100pF, 25V  | 3   | Vishay |
| C27               | C2012X5R1C105K    | Capacitor                   | 0805             | 1μF, 16V  | 1   | TDK    |
| C6, C16           | C5750X5R1H106M    | Capacitor                   | 2220             | 10μF, 50V, 2.8A                                       | 2   | TDK    |
| C9, C23           | 6TPD330M          | Capacitor                   | 7.3x4.3x 3.8mm   | $330\mu\text{F}$ , $6.3\text{V}$ , $10\text{m}\Omega$ | 2   | Sanyo  |
| C2, C11, C12, C13 | VJ1206Y103KXXAT   | Capacitor                   | 1206             | 10nF, 25V   | 4   | Vishay |
| C7, C25, C34      | VJ1206Y104KXXAT   | Capacitor                   | 1206             | 100nF, 25V  | 3   | Vishay |
| C19               | VJ1206Y822KXXAT   | Capacitor                   | 1206             | 8.2nF, 10%  | 1   | Vishay |
| C20               | VJ1206Y153KXXAT   | Capacitor                   | 1206             | 15nF, 10%   | 1   | Vishay |
| C26               | C3216X7R1C475K    | Capacitor                   | 1206             | 4.7μF, 25V  | 1   | TDK    |
| R1                | CRCW1206123J      | Resistor                    | 1206             | 12kΩ, 5%  | 1   | Vishay |
| R2, R6, R14, R16  | CRCW1206100J      | Resistor                    | 1206             | 100Ω, 5%  | 1   | Vishay |
| R13               | CRCW1206682J      | Resistor                    | 1206             | 6.8kΩ, 12%  | 1   | Vishay |
| R7, R15           | WSL-2512 .010 1%  | Resistor                    | 2512             | 10mΩ, 1W  | 2   | Vishay |
| R18, R9           | CRCW1206000Z      | Resistor                    | 1206             | 0Ω  | 2   | Vishay |
| R10               | CRCW12062261F     | Resistor                    | 1206             | 2.26kΩ, 1%  | 1   | Vishay |
| R23               | CRCW12068451F     | Resistor                    | 1206             | 8.45kΩ, 1%  | 1   | Vishay |
| R24               | CRCW12061372F     | Resistor                    | 1206             | 13.7kΩ, 1%  | 1   | Vishay |
| R11, R20          | CRCW12064991F     | Resistor                    | 1206             | 4.99kΩ, 1%  | 2   | Vishay |
| R19               | CRCW12068251F     | Resistor                    | 1206             | 8.25kΩ, 1%  | 1   | Vishay |
| R27               | CRCW12064R7J      | Resistor                    | 1206             | 4.7Ω, 5%  | 1   | Vishay |
| R28               | CRCW1206224J      | Resistor                    | 1206             | 220kΩ, 5%   | 1   | Vishay |

#### Additional Footprints (Continued) • V<sub>IN</sub> C28 C30 R1 UV-DLY VIN ILIM1 VLIN5 C34 KS1 C29 RSNS1 SYNC SYNC/ PGOOD R28 HDRV1 Q1 L1 **M** ON/SS1 SW1 . C11 S1 C7 R10 J2 CBOOT1 C8 C9 C10 D4 ON/SS2 LDRV1 C12 S2 Q2 and Q3 **PGND** FB1 C13 C14 COMP1 $V_{IN}$ C18 C19 R13 R14 ILIM2 KS2 C31 R16 R23 RSNS2 C15 J1 R26 Q4 $V_{o2}$ HDRV2 COMP2 L2 **M** SW2 C20 C21 VLIN5 R19 $V_{\mathrm{DD}}$ R18 CBOOT2 C22 C23 C24 R25 VDD1 R27 19 C26 C27 LDRV2 VDD2 Q5 and Q6 SGND FB2

FIGURE 2. Complete Resistor Sense Evaluation Board Schematic

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# Additional Footprints (Continued)

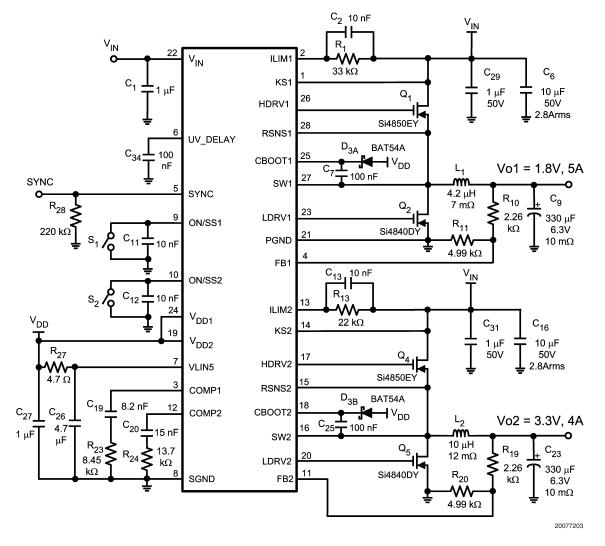


FIGURE 3. Standard  $V_{\rm DS}$  Sense Circuit

# Standard $V_{DS}$ Sense BOM

| ID                | Part Number       | Туре                        | Size             | Parameters  | Qty | Vendor |
|-------------------|-------------------|-----------------------------|------------------|---|-----|--------|
| U1                | LM5642            | Dual Synchronous Controller | TSSOP-28         |   | 1   | NSC    |
| Q1, Q4            | Si4850EY          | N-MOSFET                    | SO-8             | 60V   | 2   | Vishay |
| Q2, Q5            | Si4840DY          | N-MOSFET                    | SO-8             | 40V   | 2   | Vishay |
| D3                | BAT54A            | Schottky Diode              | SOT-23           | 30V   | 1   | ON     |
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| L2                | RLF12545T-100M5R1 | Inductor                    | 12.5x12.5x 4.5mm | 10μH, 12mΩ, 5.1A                                      | 1   | TDK    |
| C1, C29, C31      | C3216X7R1H105K    | Capacitor                   | 1206             | 1μF, 50V  | 1   | TDK    |
| C27               | C2012X5R1C105K    | Capacitor                   | 0805             | 1μF, 16V  | 1   | TDK    |
| C6, C16           | C5750X5R1H106M    | Capacitor                   | 2220             | 10μF, 50V, 2.8A                                       | 2   | TDK    |
| C9, C23           | 6TPD330M          | Capacitor                   | 7.3x4.3x 3.8mm   | $330\mu\text{F}$ , $6.3\text{V}$ , $10\text{m}\Omega$ | 2   | Sanyo  |
| C2, C11, C12, C13 | VJ1206Y103KXXAT   | Capacitor                   | 1206             | 10nF, 25V   | 4   | Vishay |
| C7, C25, C34      | VJ1206Y104KXXAT   | Capacitor                   | 1206             | 100nF, 25V  | 3   | Vishay |
| C19               | VJ1206Y822KXXAT   | Capacitor                   | 1206             | 8.2nF, 10%  | 1   | Vishay |
| C20               | VJ1206Y153KXXAT   | Capacitor                   | 1206             | 15nF, 10%   | 1   | Vishay |

# $\begin{tabular}{lll} \textbf{Additional Footprints} & (Continued) \\ \textbf{Standard $V_{DS}$ Sense BOM} & (Continued) \\ \end{tabular}$

| ID       | Part Number    | Туре      | Size | Parameters | Qty | Vendor |
|----------|----------------|-----------|------|------------|-----|--------|
| C26      | C3216X7R1C475K | Capacitor | 1206 | 4.7μF, 25V | 1   | TDK    |
| R1       | CRCW1206333J   | Resistor  | 1206 | 33kΩ, 5%   | 1   | Vishay |
| R13      | CRCW1206223J   | Resistor  | 1206 | 22kΩ, 5%   | 1   | Vishay |
| R10      | CRCW12062261F  | Resistor  | 1206 | 2.26kΩ, 1% | 1   | Vishay |
| R23      | CRCW12068451F  | Resistor  | 1206 | 8.45kΩ, 1% | 1   | Vishay |
| R24      | CRCW12061372F  | Resistor  | 1206 | 13.7kΩ, 1% | 1   | Vishay |
| R11, R20 | CRCW12064991F  | Resistor  | 1206 | 4.99kΩ, 1% | 2   | Vishay |
| R19      | CRCW12068251F  | Resistor  | 1206 | 8.25kΩ, 1% | 1   | Vishay |
| R27      | CRCW12064R7J   | Resistor  | 1206 | 4.7Ω, 5%   | 1   | Vishay |
| R28      | CRCW1206224J   | Resistor  | 1206 | 220kΩ, 5%  | 1   | Vishay |

# Additional Footprints (Continued)

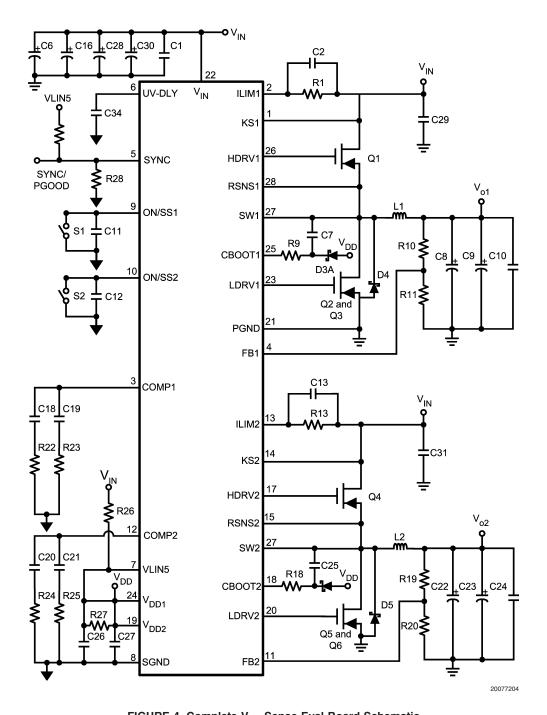


FIGURE 4. Complete  ${\rm V_{DS}}$  Sense Eval Board Schematic

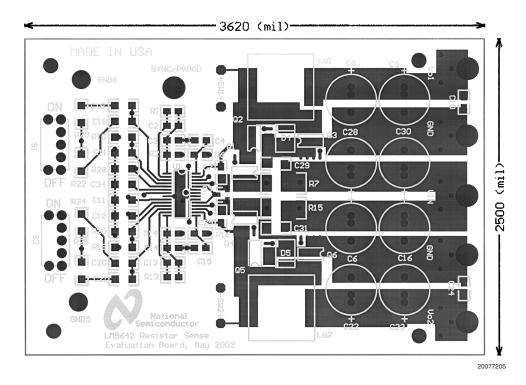


FIGURE 5. Resistor Sense PCB Top Layer

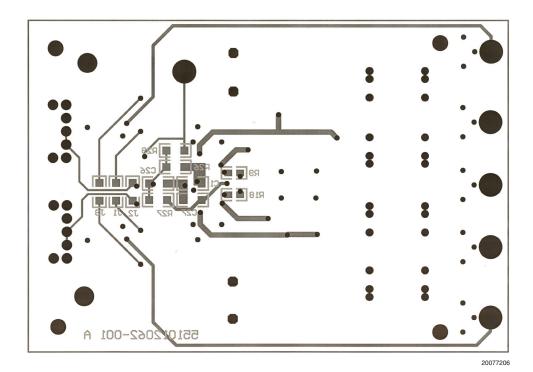
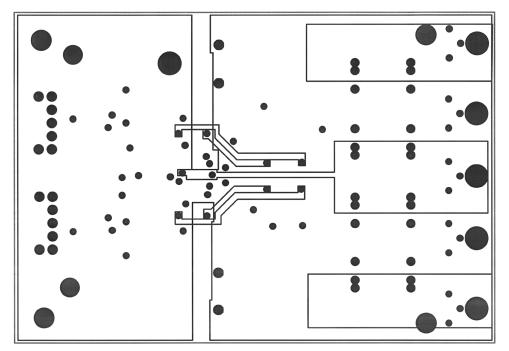


FIGURE 6. Resistor Sense PCB Bottom Layer



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FIGURE 7. Resistor Sense PCB Internal Planes

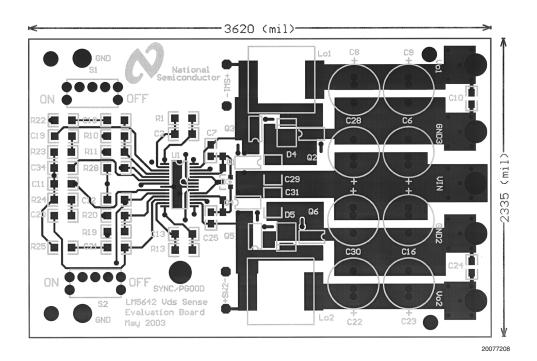
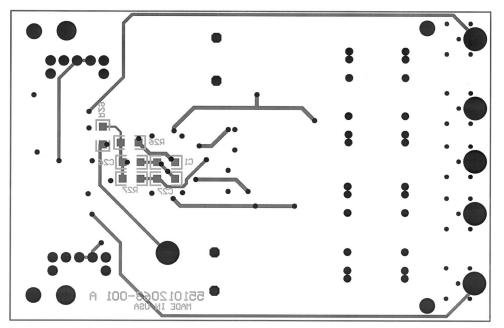
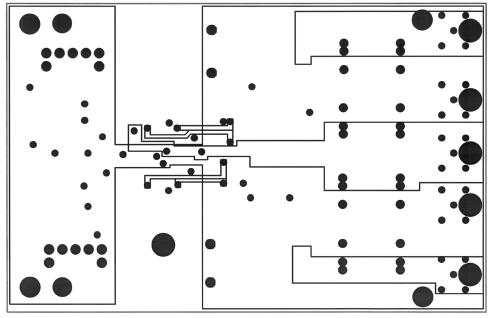


FIGURE 8.  $V_{\rm DS}$  Sense PCB Top Layer



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FIGURE 9.  $V_{\rm DS}$  Sense PCB Bottom Layer



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FIGURE 10.  ${
m V}_{
m DS}$  Sense PCB Internal Planes

# LM5642 Evaluation Board

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